

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Extended temperature range T_i = 175 °C
- · Side wettable flanks for optical solder inspection
- ElectroStatic Discharge (ESD) protection > 2 kV HBM (class H2)
- Trench MOSFET technology
- AEC-Q101 qualified

3. Applications

- LED lighting
- High-speed line driver
- Low-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	80	V
V _{GS}	gate-source voltage			-20	-	20	V
I _D	drain current	V _{GS} = 10 V; T _{sp} = 25 °C		-	-	5.1	А
P _{tot}	total power dissipation	T _{sp} = 25 °C		-	-	15	W
Static chara	cteristics		- I				
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 1.9 A; T _j = 25 °C		-	175	230	mΩ



5. Pinning information

Table 2	Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	D	drain		D				
2	D	drain						
3	G	gate		G ↓ ↓ ↓ ↓				
4	S	source	3 8 4					
5	D	drain	Transparent top view					
6	D	drain	DFN2020MD-6 (SOT1220)	s				
7	D	drain]	017aaa255				
8	S	source						

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BUK6D230-80E		plastic, leadless thermal enhanced ultra thin small outline package; 6 terminals; 0.65 mm pitch; 2 mm x 2 mm x 0.65 mm body	SOT1220			

7. Marking

Table 4. Marking codes

Type number	Marking code
BUK6D230-80E	4T

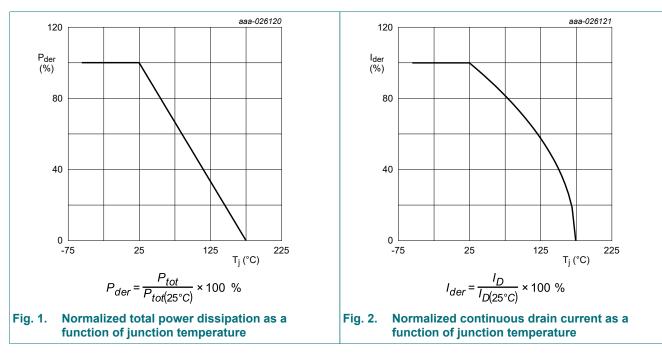
8. Limiting values

Table 5. Limiting values

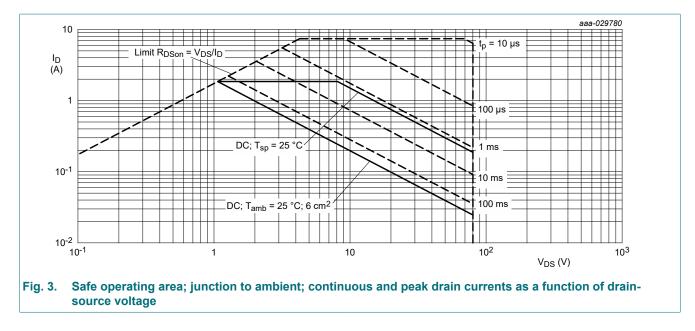
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	80	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{sp} = 25 °C		-	5.1	А
		V _{GS} = 10 V; T _{sp} = 100 °C		-	3.6	А
		V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	1.9	А
I _{DM}	peak drain current	T_{sp} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	20.4	А
P _{tot}	total power dissipation	T _{sp} = 25 °C		-	15	W
		T _{amb} = 25 °C	[1]	-	2	W
Tj	junction temperature			-55	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C
Source-draii	n diode					
ls	source current	T _{sp} = 25 °C		-	5.1	А
		T _{amb} = 25 °C	[1]	-	1.9	А
I _{SM}	peak source current	single pulse; $t_p \le 10 \ \mu s$; $T_{sp} = 25 \ ^{\circ}C$		-	20.4	А
ESD maximu	um rating		•			
V _{ESD}	electrostatic discharge voltage	НВМ	[2]	-	2000	V
Avalanche r	uggedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	T _{j(init)} = 25 °C; I _D = 0.27 A; DUT in v avalanche (unclamped)		-	11.3	mJ
	I	1		1		

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².
 Measured between all pins.



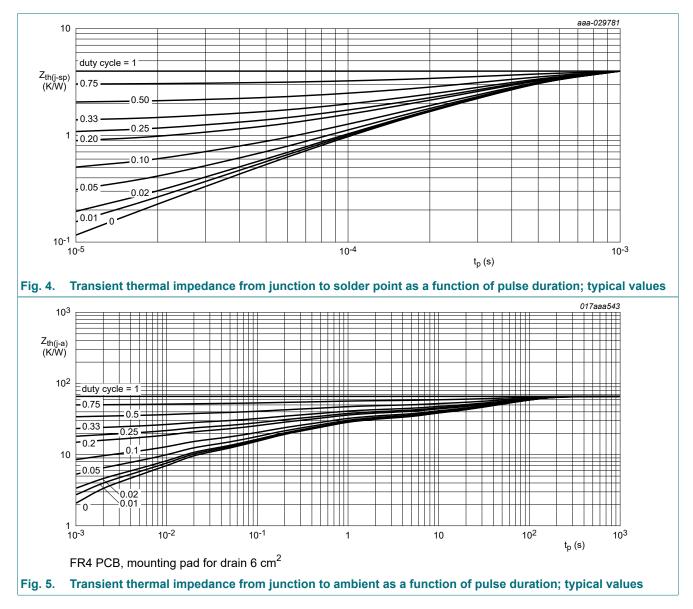
80 V, N-channel Trench MOSFET



9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	66	76	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	5	10	K/W

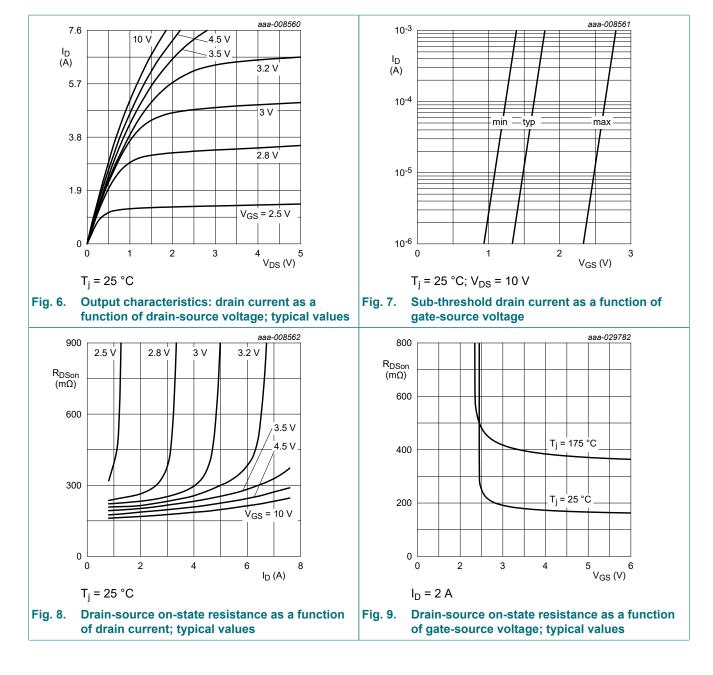
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².



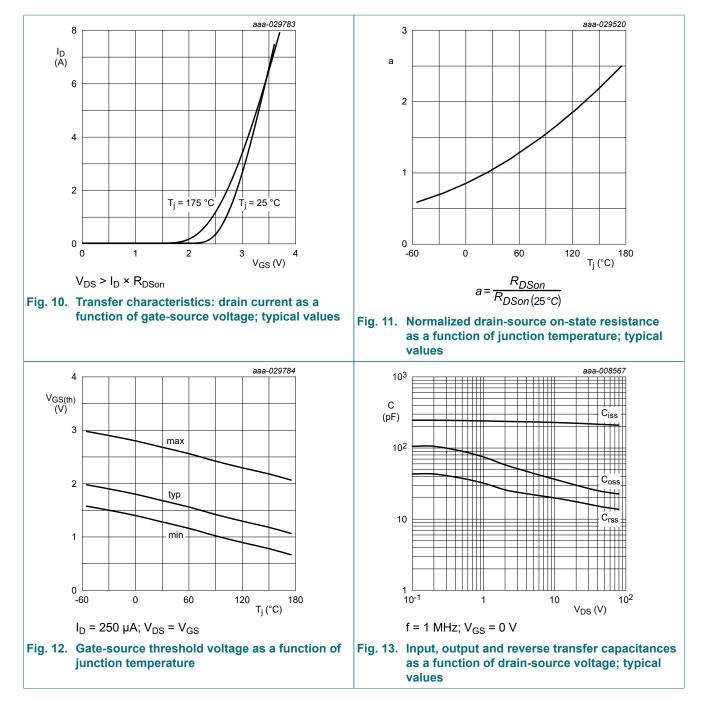
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	80	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = 250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	1.3	1.7	2.7	V
I _{DSS}	drain leakage current	V _{DS} = 80 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
		V _{DS} = 80 V; V _{GS} = 0 V; T _j = 125 °C	-	-	4	μA
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	15	μA
		V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-15	μA
		V _{GS} = 10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	1	μA
		V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-1	μA
Been	drain-source on-state	V _{GS} = 10 V; I _D = 1.9 A; T _j = 25 °C	-	175	230	mΩ
resis	resistance	V _{GS} = 10 V; I _D = 1.9 A; T _j = 175 °C	-	440	575	mΩ
		V _{GS} = 4.5 V; I _D = 1.7 A; T _j = 25 °C	-	195	275	mΩ
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 1.9 A; T _j = 25 °C	-	7	-	S
R _G	gate resistance	f = 1 MHz	-	1	-	Ω
Dynamic ch	aracteristics			_		
Q _{G(tot)}	total gate charge	V_{DS} = 40 V; I _D = 1.9 A; V _{GS} = 10 V;	-	4.8	7.2	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.6	-	nC
Q _{GD}	gate-drain charge		-	0.9	-	nC
C _{iss}	input capacitance	V _{DS} = 40 V; f = 1 MHz; V _{GS} = 0 V;	-	215	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	25	-	pF
C _{rss}	reverse transfer capacitance		-	15	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 40 V; I _D = 1.9 A; V _{GS} = 10 V;	-	3.5	-	ns
t _r	rise time	R _{G(ext)} = 6 Ω; T _j = 25 °C	-	2	-	ns
t _{d(off)}	turn-off delay time		-	9.5	-	ns
t _f	fall time		-	3	-	ns
Source-drai	n diode					
V _{SD}	source-drain voltage	I _S = 1.9 A; V _{GS} = 0 V; T _j = 25 °C	-	0.8	1.2	V
t _{rr}	reverse recovery time	I _S = 1.8 A; dI _S /dt = -100 A/µs;	-	16	-	ns
Q _r	recovered charge	V _{GS} = 0 V; V _{DS} = 40 V; T _j = 25 °C	-	7.6	-	nC

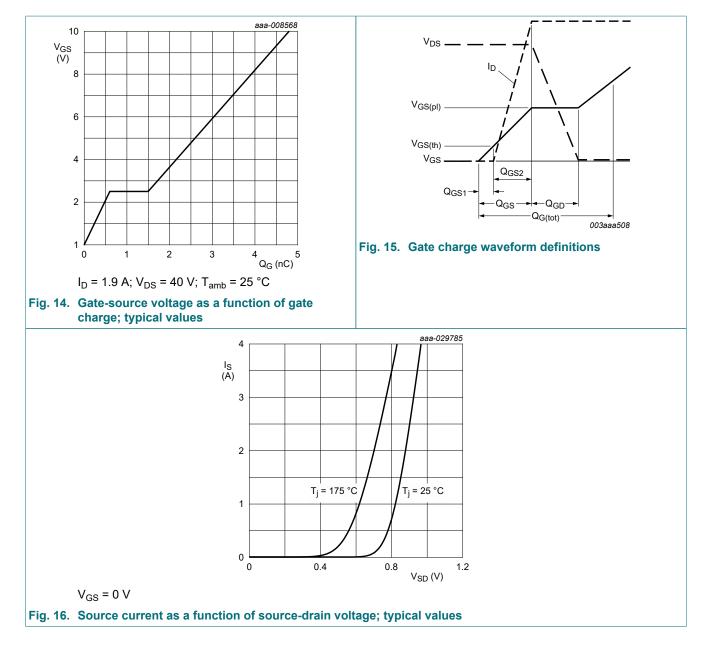
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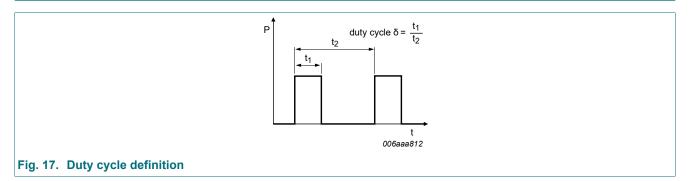
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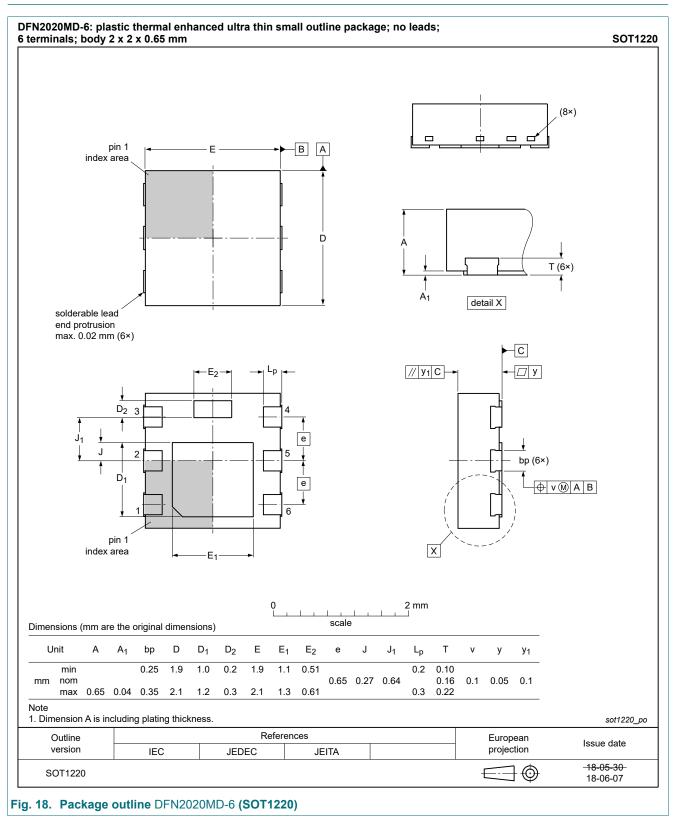
11. Test information



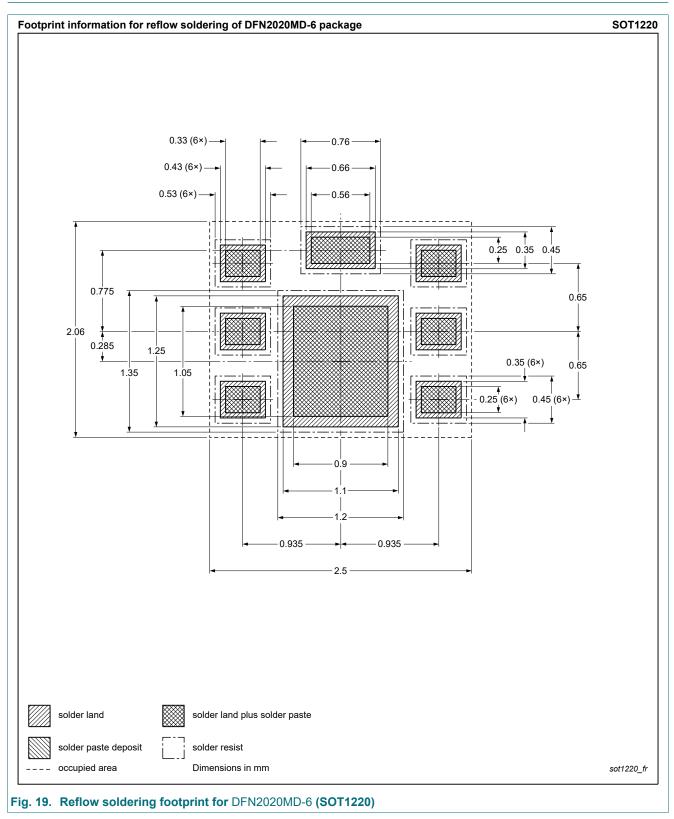
Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



13. Soldering



14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
BUK6D230-80E v.1	20190429	Product data sheet	-	-		

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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